

# **NPN High Voltage Amplifier**

This device is designed for application as a video output to drive color CRT and other high voltage applications. Sourced from Process 48.

### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CES</sub>	Collector-Emitter Voltage	300	V
V <sub>CBO</sub>	Collector-Base Voltage	300	V
V <sub>EBO</sub>	Emitter-Base Voltage	6.0	V
Ic	Collector Current - Continuous	500	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES: 1) These ratings are based on a maximum junction temperature of 150 degrees C. 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max			Units
		MPSA42	*MMBTA42	**PZTA42	
PD	Total Device Dissipation	625	350	1,000	mW
	Derate above 25°C	5.0	2.8	8.0	mW/∘C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{ ext{ hetaJA}}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

\*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

\*\* Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm<sup>2</sup>.

## NPN High Voltage Amplifier (continued)

Electrical Characteristics	TA = 25°C unless otherwise noted
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Symbol	Parameter	Test Conditions	Min	Max	Units

### OFF CHARACTERISTICS

V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	300		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = 100 \ \mu A, \ I_{E} = 0$	300		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E} = 100 \ \mu A, \ I_{C} = 0$	6.0		V
I <sub>CBO</sub>	Collector-Cutoff Current	$V_{CB} = 200 \text{ V}, I_E = 0$		0.1	μΑ
I <sub>EBO</sub>	Emitter-Cutoff Current	$V_{EB} = 6.0 \text{ V}, I_{C} = 0$		0.1	μΑ

### **ON CHARACTERISTICS\***

h <sub>FE</sub>	DC Current Gain	$I_{C} = 1.0 \text{ mA}, V_{CE} = 10 \text{ V}$	25		
		$I_{C} = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	40		
		$I_{C} = 30 \text{ mA}, V_{CE} = 10 \text{ V}$	40		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_{\rm C} = 20$ mA, $I_{\rm B} = 2.0$ mA		0.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_{\rm C} = 20$ mA, $I_{\rm B} = 2.0$ mA		0.9	V

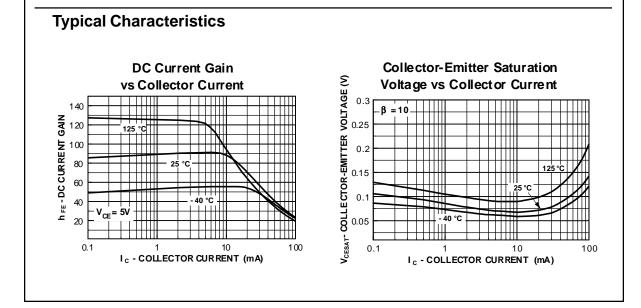
### SMALL SIGNAL CHARACTERISTICS

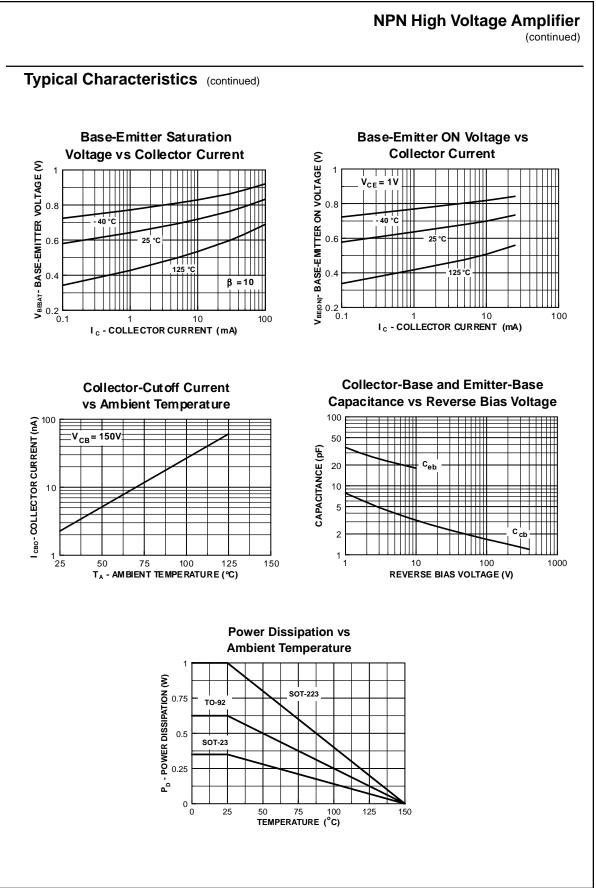
f⊤	Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	50		MHz
C <sub>cb</sub>	Collector-Base Capacitance	$V_{CB} = 20 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$		3.0	pF

\*Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%

# **Spice Model**

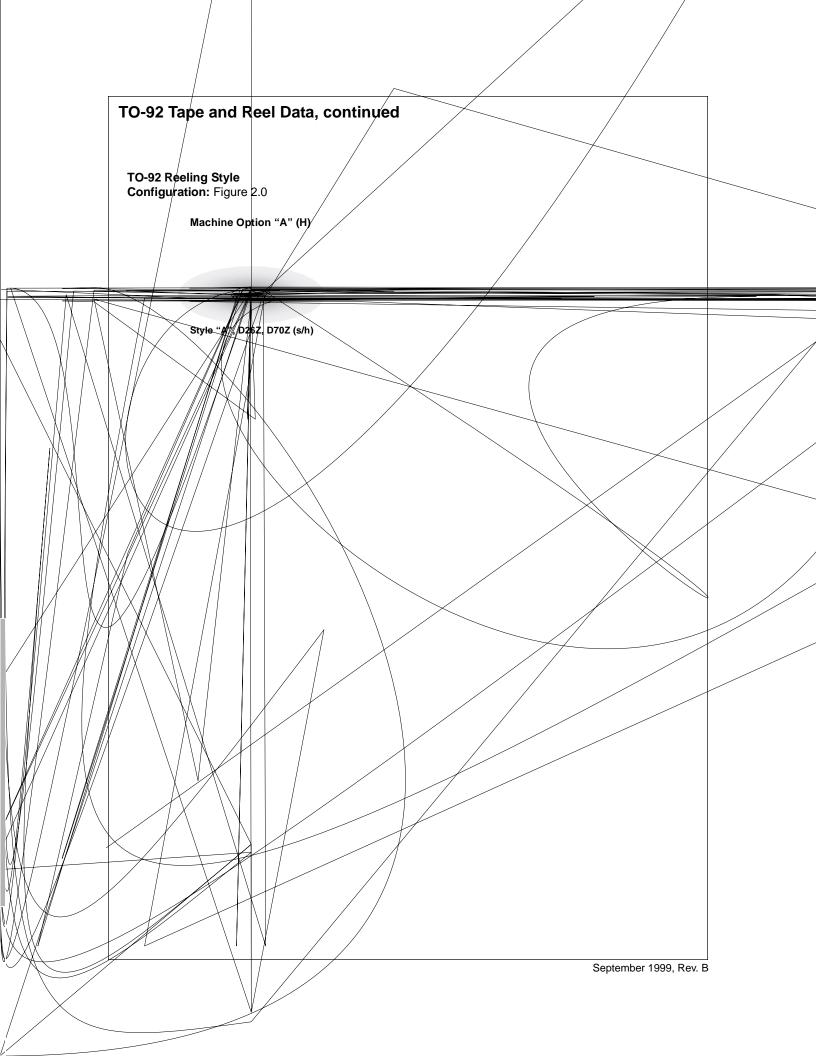
NPN (Is=34.9f Xti=3 Eg=1.11 Vaf=100 Bf=2.65K Ne=1.708 Ise=16.32p Ikf=23.79m Xtb=1.5 Br=9.769 Nc=2 Isc=0 Ikr=0 Rc=7 Cjc=14.23p Mjc=.5489 Vjc=.75 Fc=.5 Cje=49.62p Mje=.4136 Vje=.75 Tr=934.3p Tf=1.69n Itf=5 Vtf=20 Xtf=150 Rb=10)

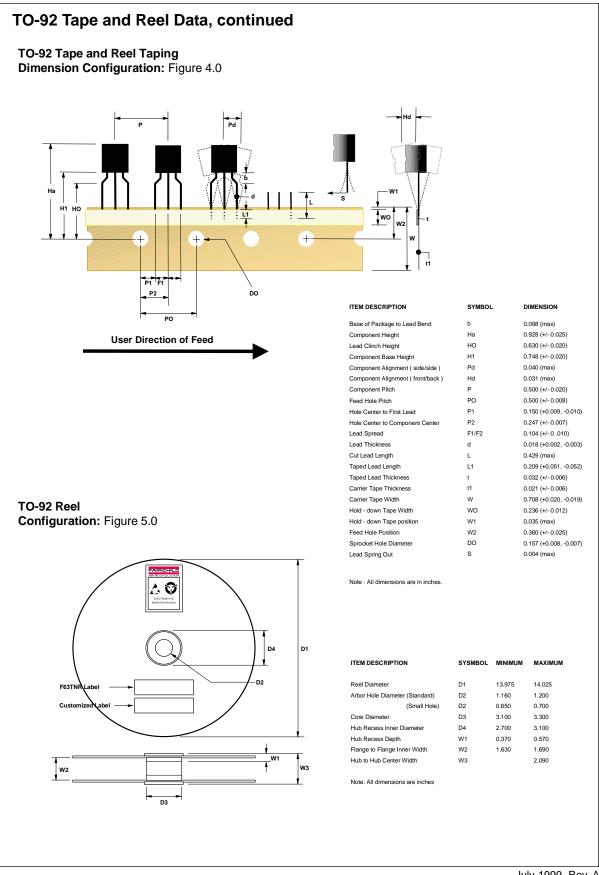




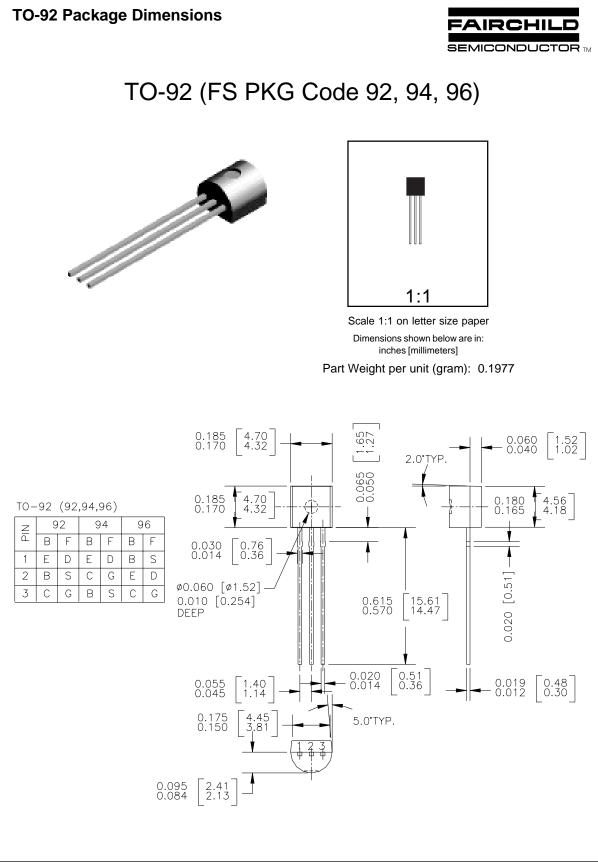
# MPSA42 / MMBTA42 / PZTA42







July 1999, Rev. A



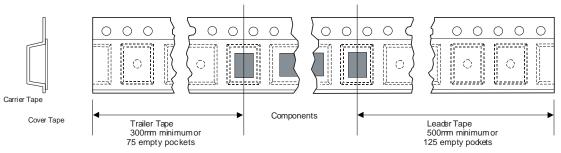
SOT-23 Packaging Configuration: Figure 10

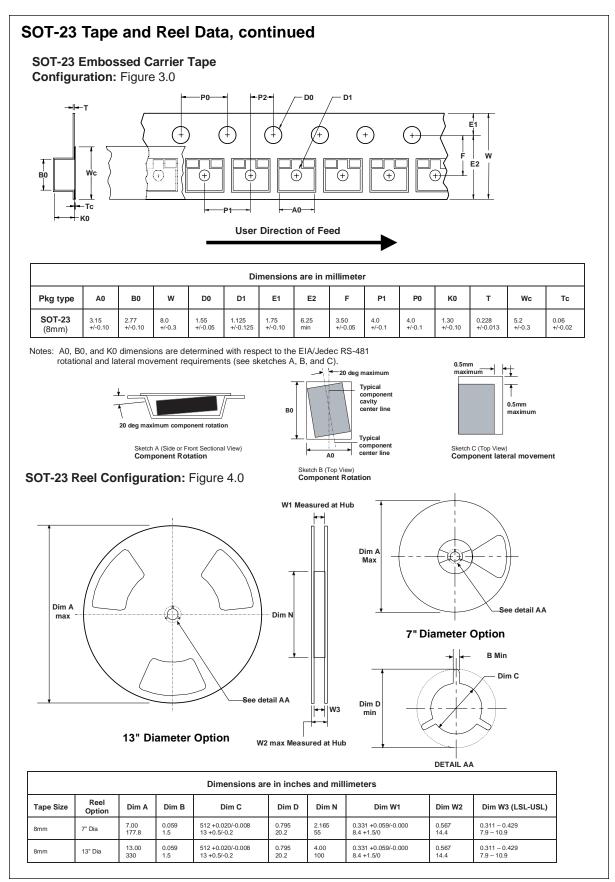
SOT-23 PackagingInformation					
PackagingOption	Standard (noflow code)	D87Z			
Packagingtype	TNR	TNR			
Qty per Reel/Tube/Bag	3,000	10,000			
Reel Size	7" Dia	13"			
Box Dimension (mm)	187x107x183	343x343x64			
Max qty per Box	24,000	30,000			
Weight per unit (gm)	0.0082	0.0082			
Weight per Reel (kg)	0.1175	0.4006			
Note/Comments					



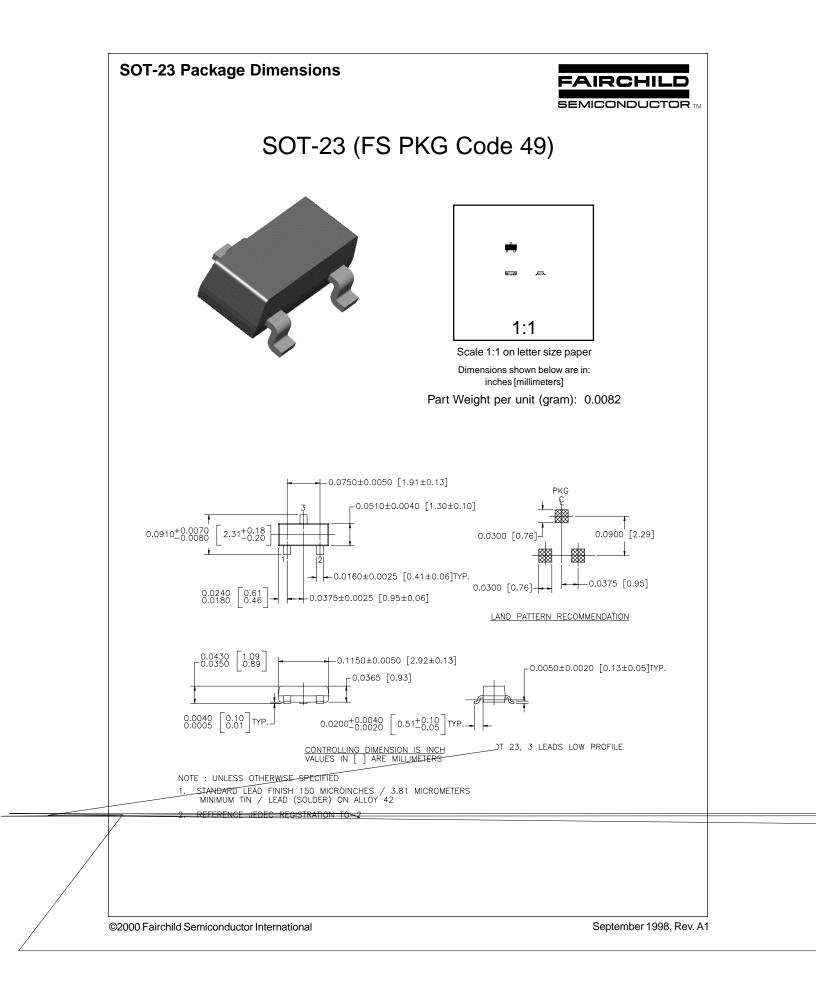


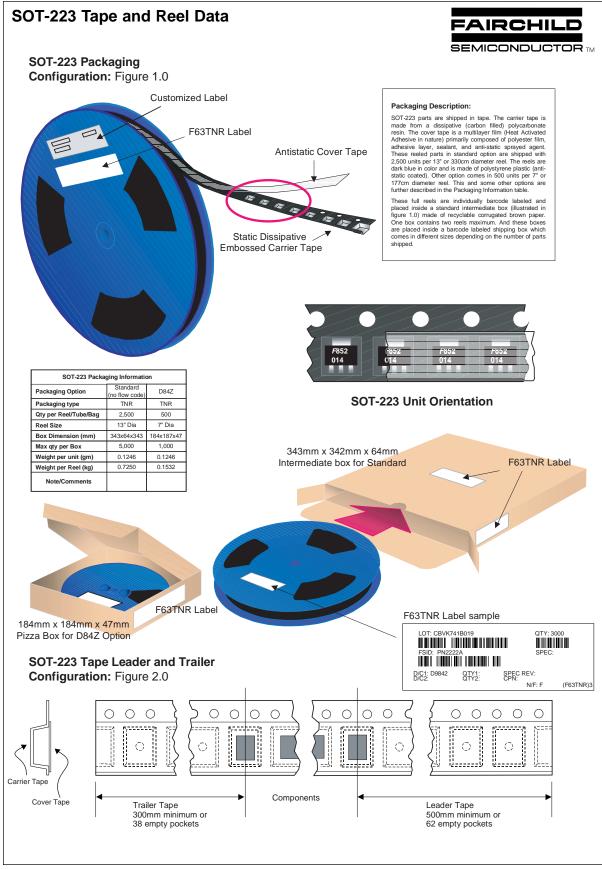
### SOT-23 Tape Leader and Trailer Configuration: Figure 20





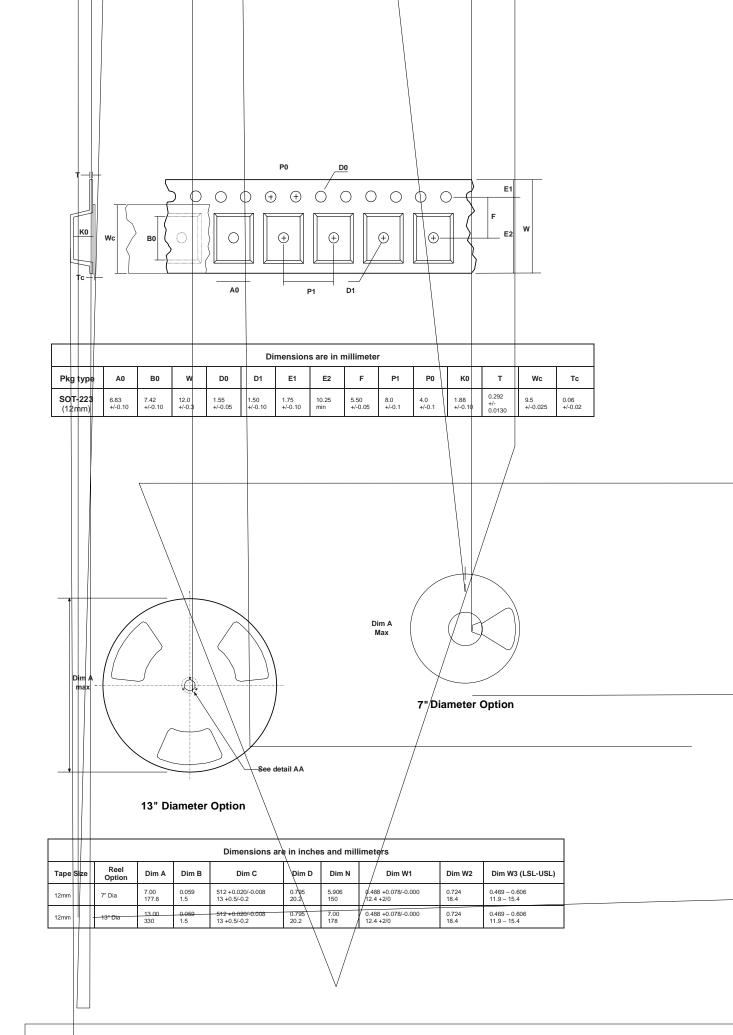
September 1999, Rev. C



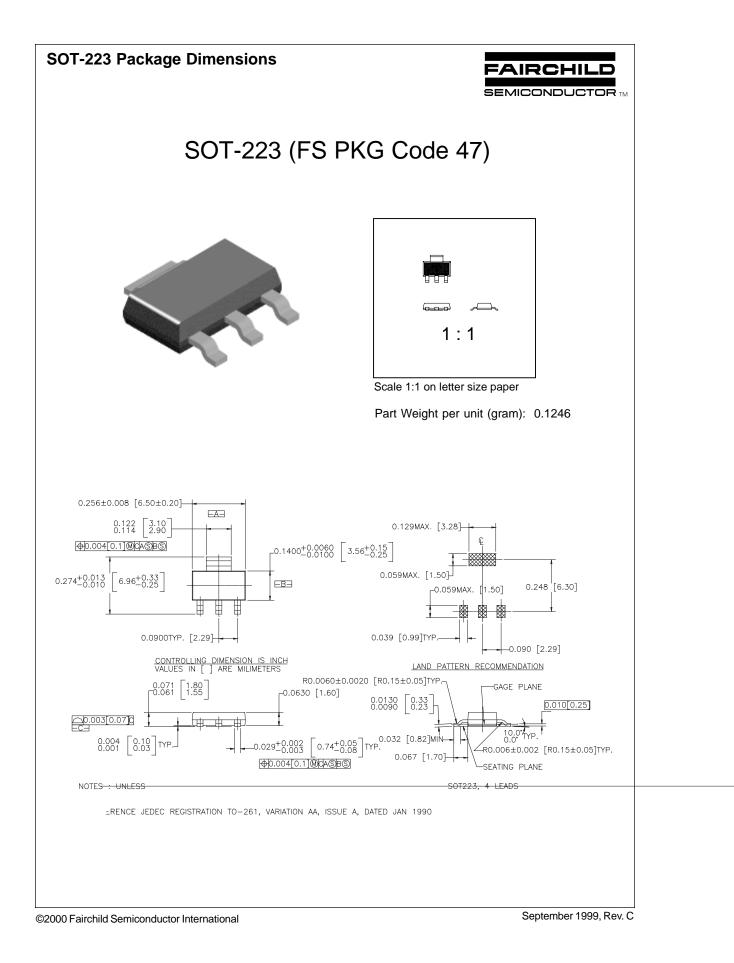


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